



### PATENT COOPERATION TREA

To:			PCT		
HAW, Yong-Noke					
8th Fl., Songchon Bidg., 642-15 Yoksam-dong, Kangnam-gu, Seoul 135-080, Republic of Korea			WRITTEN OPINION OF THE INTERNATIONAL SEARCHING AUTHORITY  (PCT Rule 43bis.1)		
·		•	Date of mailing (day/month/year)	11 MAY 2004 (11.05.2004)	
Applicant's or agent's file reference			FOR FURTHER ACTION		
FGPE04-001				See paragraph 2 below	
International application No. International filing date			(day/month/year)	Priority datc(day/month/year)	
PCT/KR2004/000153 29 JANUARY 2004 (29			0.01.2004)	29 JANUARY 2003 (29.01.2003)	
IPC7 C09K 11/59		or both national classifica			
Applicant			•		
KOREA RESEARCH	INSTITUTE OF	CHEMICAL TECHNOLO	DGY ctal		
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1. This opinion cont	ains indications rel	ating to the following item	15:		
Box No. I	Basis of the opi	nion			
Box No. II	Priority	•	•		
Box No. III	Non-establishn	nent of opinion with regar	d to novelty, inventiv	e step and industrial applicability	
Box No. IV	Box No. IV Lack of unity of invention				
X Box No. V		ment under Rule 43bis.1(aplanations supporting suc		ovelty, inventive step or industrial applicabili	
Box No. V		• • • •		•	

#### **FURTHER ACTION**

If a demand for international preliminary examination is made, this opinion will be considered to be a written opinion of the International Preliminary Examining Authority ("IPEA") except that this does not apply where the applicant chooses an Authority other than this one to be the IPEA and the chosen IPEA has notified the International Bureau under Rule 66.1 bis(b) that written opinions of this International Scarching Authority will not be so considered.

If this opinion is, as provided above, considered to be a written opinion of the IPEA, the applicant is invited to submit to the IPEA a written reply together, where appropriate, with amendments, before the expiration of 3 months from the date of mailing of Form PCT/ISA/220 or before the expiration of 22 months from the priority date, whichever expires later. For further options, see Form PCT/ISA/220.

For further details, see notes to Form PCT/ISA/220.

Name and mailing address of the ISA/KR



Korean Intellectual Property Office 920 Dunsan-dong, Seo-gu, Daejeon 302-701, Republic of Korea

Box No. VII Certain defects in the international application Box No. VIII Certain observations on the international application

Facsimile No. 82-42-472-7140

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CHOI, Soung Keun

Telephone No. 82-42-481-5575



# ITTEN OPINION OF THE INTERNATIONAL SEARCHING AUTHORITY

mational application No.

PCT/KR2004/000153

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Box	No. I Basis	of this opinion		<u> </u>				
1. V	Vith regard to hich it was t	o the language, t filed, unless other	his opinion has rwise indicated	been establish under this iten	ed on the basi n.	s of the internation	nal application i	n the language in
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### WRITTEN OPINION OF THE INTERNATIONAL SEARCHING AUTHORITY

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International application No.

PCT/KR2004/000153

Box No. V Reasoned statement under Rule 43bis.1(a)(i) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement

i.	Statement			·
	Novelty (N)	Claims	1-18	YES
		Claims		NO NO
	Inventive step (IS)	Claims	14-18	YES
		Claims	1-13	NO NO
	Industrial applicability (IA)	Claims	1-18	YES
		Claims		NO NO

#### 2. Citations and explanations:

Reference is made to the following documents:

D1: US 5.068.055 A

D2: #0 98/42798 A1 => USPN 6,093,346 is counterpart

D3: US 5,023,015 A D4: US 6,255,670 B1

#### 1. Novelty

Claims 1, 2 and 14 relate to a strontium silicate phosphor having the formula: Sr2-xSiO4:Eu2+x (x is  $0.001\le x\le 1$ ); a preparation method thereof comprising the steps of mixing strontium carbonate, silica and europium oxide, and drying and heat-treating the mixture; and a white light-emitting diode chip containing said phosphor. Said claims are different from D1-D3 in that D1-D3 contain boric acid or magnesium instead of silica as a phosphore base material. D4 includes two or more elements such as europium and neodymium as an activator. Accordingly, said claims are also different from D4 in the method of preparing a phosphor and the configuration of a diode chip containing said phosphor.

Therefore, independent claims 1, 2 and 14 are considered to be novel (PCT Article 33(2)), and claims 3-13 and 15-18 which refer to claims 1, 2 and 14 are also considered to be novel.

#### 2 Inventive Step

D1, D3 and D4 describe a method for preparing a boric phosphor comprising the steps of mixing strontium carbonate, boric acid and europium oxide, and drying and heat-treating the mixture. Accordingly, the present application is different from said documents in the constituent element of a base material, that is, in the composition of a phosphor containing silica. However, D2 describes a method for preparing a silicate phosphor by mixing silica and magnesium with strontium. In addition, there is no difference between the present application and D1, D3 and D4 in the drying temperature and time and in the heat-treatment temperature and time.

(continuied on supplemental sheet)

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#### Supplemental Box

#### Continuation of:

Accordingly, the strontium carbonate phosphor and the preparation method thereof claimed in claims 1-13 can be readily invented from said prior art. But claims 14-18 are different from the prior art in that the strontium carbonate phosphor is formed in the outer portion of a diode and molding-treated by a resin, and in the effect of a white light-emitting diode chip having a wide wavelength range.

Therefore, claims 1-13 are considered to lack an inventive step (PCT Article 33(3), but claims 14-18 are considered to involve an inventive step.